



SPECIFICATION (Reference sheet)

• Supplier : Samsung electro-mechanics • Samsung P/N : CL05B563KO5NNNC

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 56nF, ±10%, 16V, X7R, 0402

A. Samsung Part Number

<u>CL</u> <u>05</u> <u>B</u> <u>563</u> <u>K</u> <u>O</u> <u>5</u> <u>N</u> <u>N</u> <u>N</u> <u>C</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor		
2	Size	0402 (inch code)	L: 1.0 ± 0.05 mm	W: 0.5 ± 0.05 mm
3	Dielectric	X7R	8 Inner electrode	Ni
4	Capacitance	56 nF	Termination	Cu
⑤	Capacitance	±10%	Plating	Sn 100% (Pb Free)
	tolerance		9 Product	Normal
6	Rated Voltage	16 V	10 Special	Reserved for future use
7	Thickness	0.5 ± 0.05 mm	11 Packaging	Cardboard Type, 7" reel

B. Samsung Reliability Test and Judgement condition

	Performance	Test condition	
Capacitance	Within specified tolerance	1kHz±10% 1.0±0.2Vrms	
Tan δ (DF)	0.035 max.		
Insulation	10,000Mohm or 100Mohm.µF	Rated Voltage 60~120 sec.	
Resistance	Whichever is Smaller		
Appearance	No abnormal exterior appearance	Microscope (×10)	
Withstanding	No dielectric breakdown or	250% of the rated voltage	
Voltage mechanical breakdown			
Temperature X7R			
Characteristics	(From -55℃ to 125℃, Capacitance change should be within ±15%)		
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.	
of Termination	terminal electrode		
Bending Strength	Capacitance change: within ±12.5%	Bending to the limit (1mm)	
		with 1.0mm/sec.	
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder	
	is to be soldered newly	245±5℃, 3±0.3sec.	
		(preheating : 80~120 ℃ for 10~30sec.)	
Resistance to Capacitance change: within ±7.5%		Solder pot : 270±5℃, 10±1sec.	
Soldering heat	Tan δ, IR : initial spec.		

	Performance	Test condition	
Vibration Test Capacitance change: within ±5%		Amplitude : 1.5mm	
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)	
		2hours × 3 direction (x, y, z)	
Moisture	Capacitance change: within ±12.5%	With rated voltage	
Resistance Tan δ: 0.05 max		40±2℃, 90~95%RH, 500+12/-0hrs	
	IR: 500Mohm or 25Mohm · μF		
	Whichever is Smaller		
High Temperature	Capacitance change: within ±12.5%	With 200% of the rated voltage	
Resistance	Tan δ : 0.05 max	Max. operating temperature	
	IR: 1000Mohm or 50Mohm $\cdot \mu$ F		
	Whichever is Smaller	1000+48/-0hrs	
Temperature	Capacitance change: within ±7.5%	1 cycle condition	
Cycling	Tan δ, IR : initial spec.	Min. operating temperature \rightarrow 25 $^{\circ}$ C	
		$ ightarrow$ Max. operating temperature $ ightarrow$ 25 $^{\circ}$ C	
		5 cycle test	

C. Recommended Soldering method:

Reflow (Reflow Peak Temperature : 260+0/-5°C, 10sec. Max)



A Product specifications included in the specifications are effective as of March 1, 2013.

Please be advised that they are standard product specifications for reference only.

We may change, modify or discontinue the product specifications without notice at any time.

So, you need to approve the product specifications before placing an order.

Should you have any question regarding the product specifications,

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CGA2B2C0G1H060D CGA2B2C0G1H070D CGA2B2C0G1H151J CGA2B2C0G1H1R5C CGA2B2C0G1H2R2C CGA2B2C0G1H3R3C

CGA2B2C0G1H680J CGA2B2C0G1H6R8D CGA2B2X8R1H221K CGA2B2X8R1H472K CGA3E1X7R1C474K

CGA3E2C0G1H561JT0Y0N